

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	281	(257/E29.131).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/03/17 01:34
L2	184	(257/E29.131).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:36
L3	407	(257/E29.256).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:42
L4	1164	(257/E29.257).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:46
L5	534	(257/E29.26).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:54
L6	707	(257/328-329).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:56
L7	721	(257/330-331).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:57
L8	331	(257/332-333).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 01:58

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L9	492	(257/335).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 02:05
L10	250	semiconductor and (gate\$3 with (trench or recess or groove)) and @ad<"19990530" and (grad\$4 with (dop\$4 or ion or impurities or diffusion)).	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/03/17 02:00
L11	306	semiconductor and (gate\$3 with (trench or recess or groove)) and @ad<"19990530" and (grad\$6 with (dop\$4 or ion or impurities or diffusion))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/03/17 02:00
L12	53	semiconductor and (gate\$3 with (trench or recess or groove)) and @ad<"19990530" and (gate with bus)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/03/17 02:04
L13	78	(257/611).ccls. and @ad<"19990530"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/17 02:06
L14	2	("20020135014").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/03/17 02:06